

## **TIP32 Series(TIP32/32A/32B/32C)**

### **Medium Power Linear Switching Applications**

• Complement to TIP31/31A/31B/31C



#### 1.Base 2.Collector 3.Emitter

## **PNP Epitaxial Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage : TIP32	- 40	V
	: TIP32A	- 60	V
	: TIP32B	- 80	V
	: TIP32C	- 100	V
V <sub>CEO</sub>	Collector-Emitter Voltage : TIP32	- 40	V
	: TIP32A	- 60	V
	: TIP32B	- 80	V
	: TIP32C	-100	V
V <sub>EBO</sub>	Emitter-Base Voltage	- 5	V
I <sub>C</sub>	Collector Current (DC)	- 3	Α
I <sub>CP</sub>	Collector Current (Pulse)	- 5	А
I <sub>B</sub>	Base Current	- 3	Α
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	40	W
P <sub>C</sub>	Collector Dissipation (T <sub>a</sub> =25°C)	2	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
V <sub>CEO</sub> (sus)	* Collector-Emitter Sustaining Voltage				
	: TIP32	$I_C = -30 \text{mA}, I_B = 0$	-40		V
	: TIP32A		-60		V
	: TIP32B		-80		V
	: TIP32C		-100		V
CEO	Collector Cut-off Current				
	: TIP32/32A	$V_{CE} = -30V, I_{B} = 0$		- 0.3	mA
	: TIP32B/32C	$V_{CE} = -60V, I_{B} = 0$		- 0.3	mA
CES	Collector Cut-off Current				
	: TIP32	$V_{CE} = -40V, V_{EB} = 0$		- 200	μΑ
	: TIP32A	$V_{CE} = -60V, V_{EB} = 0$		- 200	μΑ
	: TIP32B	$V_{CE} = -80V, V_{EB} = 0$		- 200	μΑ
	: TIP32C	$V_{CE} = -100V, V_{CE} = 0$		- 200	μΑ
ЕВО	Emitter Cut-off Current	$V_{EB} = -5V, I_{C} = 0$		- 1	mA
h <sub>FE</sub>	* DC Current Gain	$V_{CE} = -4V, I_{C} = -1A$	25		
		$V_{CE} = -4V, I_{C} = -3A$	10	50	
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	$I_C = -3A$ , $I_B = -375mA$		- 1.2	V
V <sub>BE</sub> (sat)	* Base-Emitter Saturation Voltage	V <sub>CE</sub> = - 4V, I <sub>C</sub> = - 3A		- 1.8	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CF} = -10V, I_{C} = -500mA$	3.0		MHz

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# **Typical Characteristics**

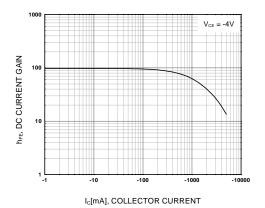


Figure 1. DC current Gain

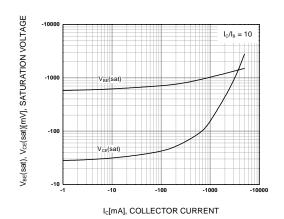


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

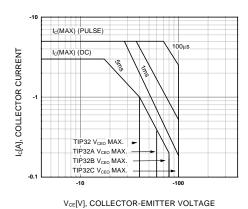


Figure 3. Safe Operating Area

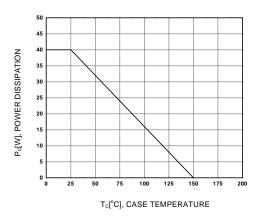
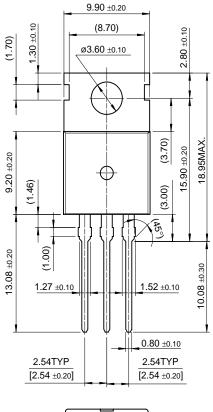


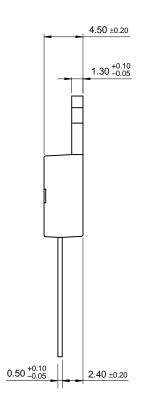
Figure 4. Power Derating

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### **Package Demensions**

### TO-220





10.00 ±0.20

Dimensions in Millimeters

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